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5 and ((pair two) near3 (contact adj. plug))

	U	I	Document ID	Issue Date	Pages	Title	Current	Cur Re	Inventor	S	C	P	2	3
1	<input type="checkbox"/>	<input type="checkbox"/>	US 20030234411 A1	20031225	14	SEMICONDUCTOR DE	257/295	257/	Kanaya, Hiroyuki et	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
2	<input type="checkbox"/>	<input type="checkbox"/>	US 20030042522 A1	20030306	27	Semiconductor memory	257/298	257/	Mikawa, Takumi et	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
3	<input type="checkbox"/>	<input type="checkbox"/>	US 20010022372 A1	20010920	63	Semiconductor device ha	257/295	257/	Kanaya, Hiroyuki et	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
4	<input type="checkbox"/>	<input type="checkbox"/>	US 6620672 B1	20030916	17	SOI DRAM with buried	438/239	438/	Dennison, Charles	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
5	<input type="checkbox"/>	<input type="checkbox"/>	US 6518120 B2	20030211	9	Capacitor and method of	438/244	257/	Park, Jong Bum	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
6	<input type="checkbox"/>	<input type="checkbox"/>	US 6190957 B1	20010220	43	Method of forming a ferr	438/240	257/	Mochizuki, Hiroshi	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>